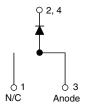


HALOGEN

FREE

HEXFRED®, Ultrafast Soft Recovery Diode, 4 A





| DPAK | (TO-252AA) |
|------|------------|
|------|------------|

| PRIMARY CHARACTERISTICS | | | |
|----------------------------------|-----------------|--|--|
| I _{F(AV)} | 4 A | | |
| V_{R} | 600 V | | |
| V _F at I _F | 1.4 V | | |
| t _{rr} typ. | 17 ns | | |
| T _J max. | 150 °C | | |
| Package | DPAK (TO-252AA) | | |
| Circuit configuration | Single | | |

FEATURES

- · Ultrafast recovery time
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- Guaranteed avalanche
- Specified at operating temperature
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- · Higher frequency operation
- · Reduced snubbing
- · Reduced parts count

DESCRIPTION / APPLICATIONS

These diodes are optimized to reduce losses and EMI / RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for freewheeling, flyback, power converters, motor drives, and other applications where high speed and reduced switching losses are design requirements.

| ABSOLUTE MAXIMUM RATINGS | | | | |
|---|-----------------------------------|-------------------------|-------------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Cathode to anode voltage | V_{RRM} | | 600 | V |
| Maximum continuous forward current | I _{F(AV)} | T _C = 100 °C | 4 | |
| Single pulse forward current | I _{FSM} | | 25 | Α |
| Repetitive peak forward current | I _{FRM} | T _C = 116 °C | 16 | |
| Maximum power dissipation | P_{D} | T _C = 100 °C | 10 | W |
| Operating junction and storage temperatures | T _J , T _{Stg} | | -55 to +150 | °C |



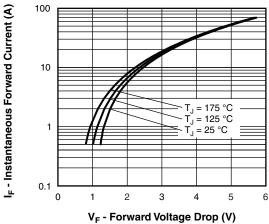


| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | |
|--|-------------------------------------|---|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | Ι _R = 100 μΑ | 600 | - | - | |
| Forward voltage See fig. 1 | | I _F = 4 A | - | 1.5 | 1.8 | V |
| | V_{F} | I _F = 8 A | - | 1.8 | 2.2 | |
| occ lig. 1 | | I _F = 4 A, T _J = 125 °C | - | 1.4 | 1.7 | |
| Maximum reverse | | $V_R = V_R$ rated | - | 0.17 | 3.0 | |
| leakage current | I _R | $T_J = 125$ °C, $V_R = 0.8 \times V_R$ rated | - | 44 | 300 | μA |
| Junction capacitance | C _T | V _R = 200 V | - | 4 | 8 | pF |
| Series inductance | L _S | Measured lead to lead 5 mm from package body | - | 8.0 | - | nΗ |

| DYNAMIC RECOVERY CHARACTERISTICS (T _C = 25 °C unless otherwise specified) | | | | | | | |
|---|-------------------------|--|--|------|------|--------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| | | $I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{A}, V_R = 30 \text{ V}$ | | - | 17 | - | |
| Reverse recovery time | t _{rr} | T _J = 25 °C | l _F = 4 A dl _F /dt = 200 A/μs V _R = 200 V | - | 28 | 42 | ns |
| | | T _J = 125 °C | | - | 38 | 57 | |
| Peak recovery current I _{RRM} | | T _J = 25 °C | | - | 2.9 | 5.2 | A |
| | IRRM | T _J = 125 °C | | - | 3.7 | 6.7 | |
| Dougrap recovery charge | 0 | T _J = 25 °C | | - | 40 | 60 | nC |
| Reverse recovery charge Q _r | Q_{rr} | T _J = 125 °C | | - | 70 | 105 | 110 |
| Rate of fall of recovery current dI _{(rec)M} /dt | -II /-IA | T _J = 25 °C | | - | 280 | - | Λ/μο |
| | T _J = 125 °C | 1 | - | 235 | - | - A/μs | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|-----------------------------------|----------------------------|--------------|--------|------------|------------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -55 | - | 150 | °C |
| Thermal resistance, junction to case | R _{thJC} | | - | - | 5.0 | °C/W |
| Thermal resistance, junction to ambient | R _{thJA} | Typical socket mount | - | - | 80 | C/VV |
| Weight | | | - | 2.0 | - | g |
| Weight | | | - | 0.07 | - | OZ. |
| Mounting torque | | | 6.0 (5.0) | - | 12 (10) | kgf · cm (lbf · in) |
| Marking device | | Case style DPAK (TO-252AA) | | HFA04S | SD60SH | |







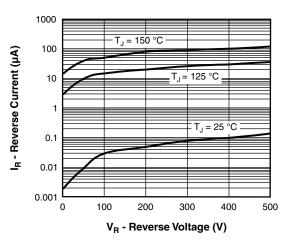


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

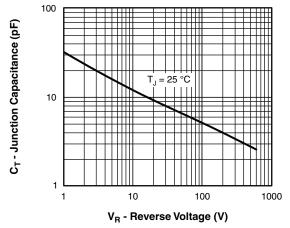


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

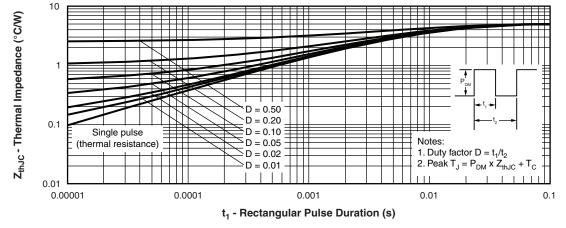


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



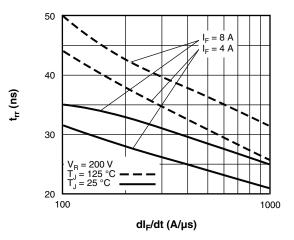


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt

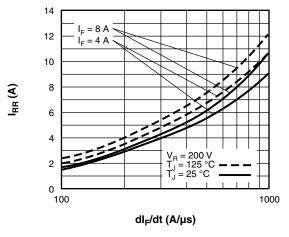


Fig. 6 - Typical Recovery Current vs. dl_F/dt

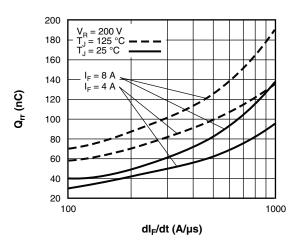


Fig. 7 - Typical Stored Charge vs. dl_F/dt

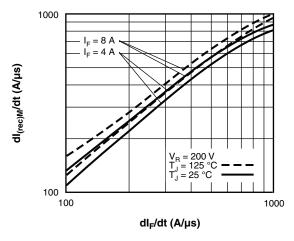


Fig. 8 - Typical $dI_{(rec)M}/dt$ vs. dI_F/dt



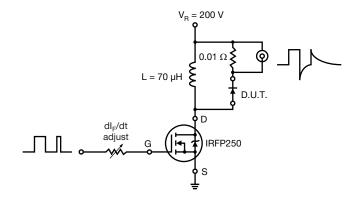
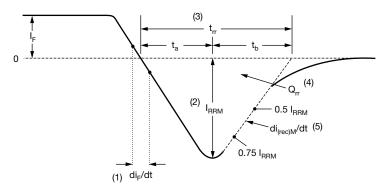


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm l_{rr}$ to point where a line passing through 0.75 $\rm l_{RRM}$ and 0.50 $\rm l_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

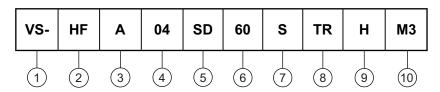
(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

HEXFRED® family

3 4 5 6 Electron irradiated

Current rating (04 = 4 A)

D-PAK

Voltage rating (60 = 600 V)

S = D-PAK

• TR = tape and reel

• R = tape and reel (right oriented)

• L = tape and reel (left oriented)

H = AEC-Q101 qualified

Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | |
|--------------------------------|------------------|------------------------|-------------------------|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | |
| VS-HFA04SD60SHM3 | 75 | 3000 | Antistatic plastic tube | | |
| VS-HFA04SD60STRHM3 | 2000 | 2000 | 13" diameter reel | | |
| VS-HFA04SD60STRRHM3 | 3000 | 3000 | 13" diameter reel | | |
| VS-HFA04SD60STRLHM3 | 3000 | 3000 | 13" diameter reel | | |

| LINKS TO RELATED DOCUMENTS | | | |
|--|--------------------------|--|--|
| Dimensions <u>www.vishay.com/doc?95519</u> | | | |
| Part marking information | www.vishay.com/doc?95518 | | |
| Packaging information | www.vishay.com/doc?95033 | | |



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Vishay

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